# Tu-I-SSP-04 Ferromagnetic Josephson Junctions for Cryogenic Memory

Norman Birge, Michigan State University in collaboration with Northrop Grumman Corporation and Arizona State University

(with thanks to D. Scott Holmes, Booz Allen Hamilton & IARPA)

The project depicted was or is supported in part by the U.S. Army Research Office and/or the Department of Energy. The information depicted does not necessarily reflect the position or the policy of the Government, and no official endorsement should be construed.

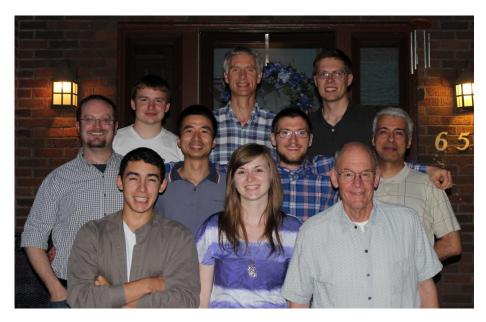






# The group

Eric Gingrich, Bethany Niedzielski, Joseph Glick, Yixing Wang, Bill Martinez, Josh Willard, Sam Edwards, Reza Loloee, William P. Pratt, Jr., plus many earlier students!

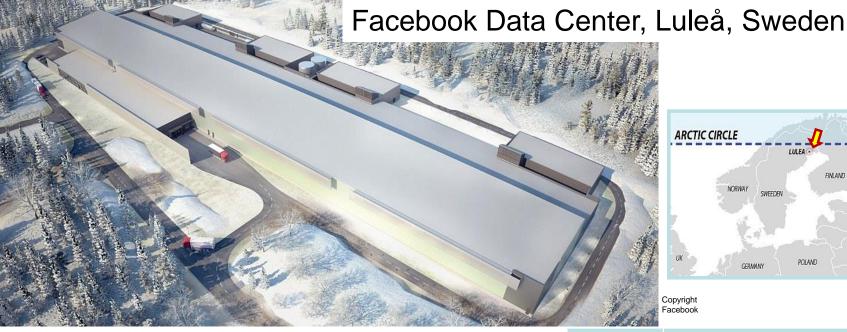


An old picture...

## **Outline**

- The need for energy-efficient computing
- Superconducting memory: JMRAM
- Superconducting/ferromagnetic hybrid systems
- Demonstration of phase control of an S/F/S
   Josephson junction the basic memory device
- Future prospects

# The need for energy-efficient computing



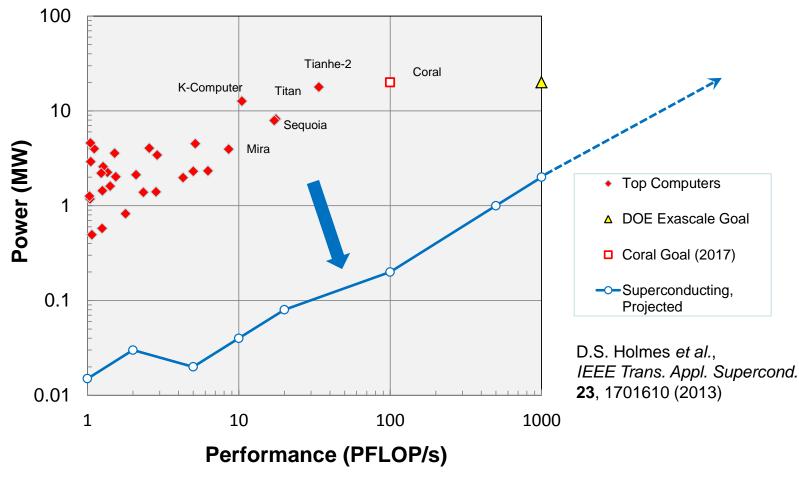
- Opened in 2013
- Cost: ~760 M\$
- Nearby Lule River generates
   9% of Sweden's electricity (~4.23 GW)
- Average annual temperature: 1.3 °C

Specifications					
27-51 PFLOP/s					
<b>21-27</b> PB RAM <b>1900-6800</b> PB disk					
84 MW avg* (120 MW max)					
<b>290,000</b> ft <sup>2</sup> (27,000 m <sup>2</sup> )					
~1.07 PUE					

<sup>\*</sup> estimated

# Superconducting computing looks promising





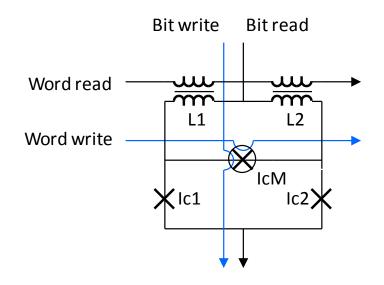
## Our approach to superconducting memory:



# Josephson Magnetic Random Access Memory (JMRAM)

Anna Y. Herr & Quentin P. Herr, US Patent 8,270,209 (2012) A.Y. Herr, Q.P. Herr & Ofer Naaman, US Patent 9,208,861 (2015)

#### Northrop Grumman Corporation



Memory cell is a SQUID loop

One junction has two stable phase states for "0" and "1"

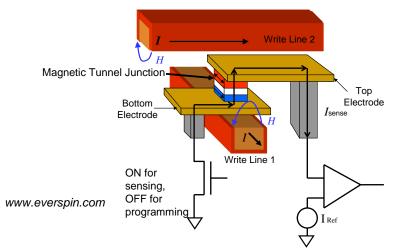
Magnetic states are written using standard MRAM techniques

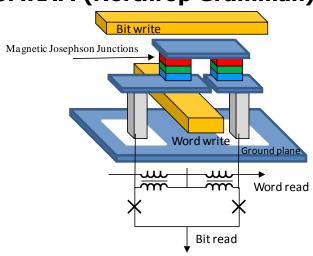
# JMRAM is a Superconducting MRAM











#### Memory cell is a Josephson junction containing a magnetic spin valve

memory state – spin-valve state sets junction phase

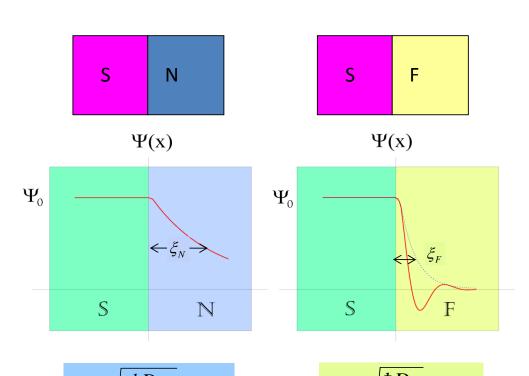
write – magnetization reversal

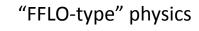
read – Josephson effect

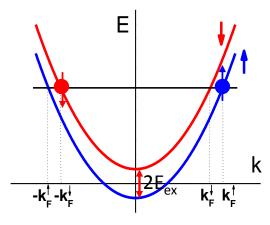
No idle/static power dissipation, read energy is dissipated only for logical "1"

## Superconductor/Ferromagnet proximity effect









$$k_F^{\uparrow} - k_F^{\downarrow} \equiv Q \approx 2 E_{ex} / \hbar v_F$$

$$\xi_F = Q^{-1} = \frac{\hbar v_F}{2E_{ex}} \qquad \text{ballistic}$$

$$\xi_F = \sqrt{\frac{\hbar D_F}{E_{ex}}}$$
 diffusive

### Consequence: S/F/S Josephson junctions oscillate between 0 and $\pi$ junctions as d<sub>F</sub> increases:

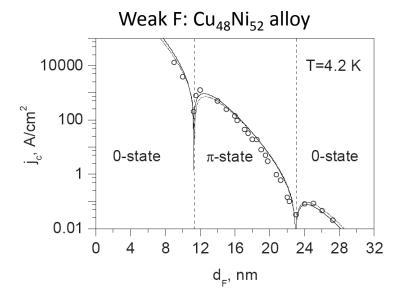
Buzdin, Bulaevskii, & Panyukov (1982).



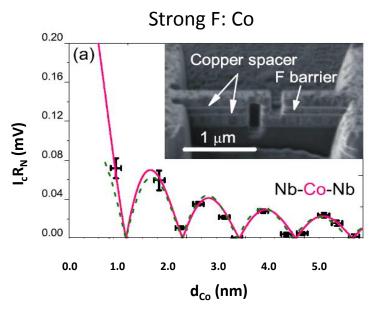
$$\xi_F = \sqrt{\frac{\hbar D_F}{E_{ex}}}$$

O-state:  $I_s = I_c \sin(\phi_2 - \phi_1)$ 

 $\pi$ -state:  $I_s = I_c sin(\phi_2 - \phi_1 + \pi)$ 



Ryazanov et al., PRL **86**, 2427 (2001); PRL **96**, 197003 (2006).



S

 $\phi_1$ 

F

S

 $\phi_2$ 

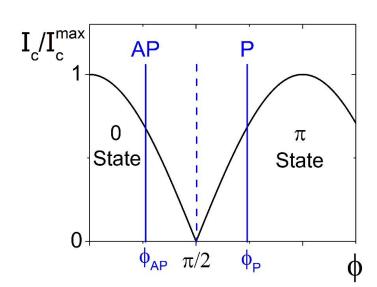
Robinson, Piano, Burnell, Bell, Blamire, PRL **97**, 177003 (2005)

Can we control I<sub>c</sub> or phase state of a single Josephson junction?

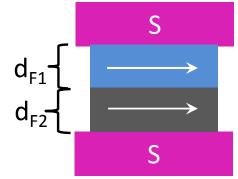
## Add a second ferromagnetic layer: S/F<sub>1</sub>/F<sub>2</sub>/S

I<sub>c</sub> and phase depend on relative magnetization direction

Electron pair accumulates phase \$\phi\$ while traversing junction

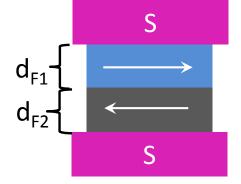


Parallel state:  $\phi = \frac{d_{F1}}{\xi_{F1}} + \frac{d_{F2}}{\xi_{F2}}$ 



Antiparallel state:  $\phi = \frac{d_{F1}}{\xi_{F1}} - \frac{d_{F2}}{\xi_{F2}}$ 

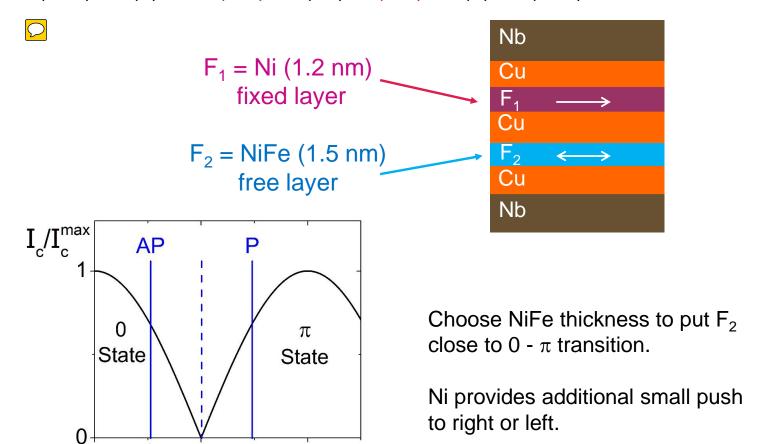
$$I_{c} \propto exp[-(d_{F1}/\xi_{F1} + d_{F2}/\xi_{F2})] \mid cos(d_{F1}/\xi_{F1} \pm d_{F2}/\xi_{F2}) \mid$$



## S/F<sub>1</sub>/N/F<sub>2</sub>/S Josephson Junction Composition

Nb(100)/Cu(5)/NiFe(1.5)/Cu(10)/Ni(1.2)/Cu(5)/Nb(150)

 $\phi_{AP} \pi/2$ 





# Two junctions in a SQUID loop used to measure relative junction phase

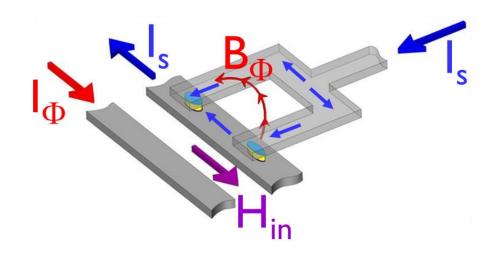
#### **Schematic:**

# Switching field $H_1$ $H_1 < H_2$ $\Re$ Switching field $H_2$

Junction sizes: Both have Area =  $0.5 \mu m^2$ Aspect Ratios = 2.2 and 2.8

#### **Cartoon of Actual Device:**

On-chip current line couples magnetic flux into SQUIDs

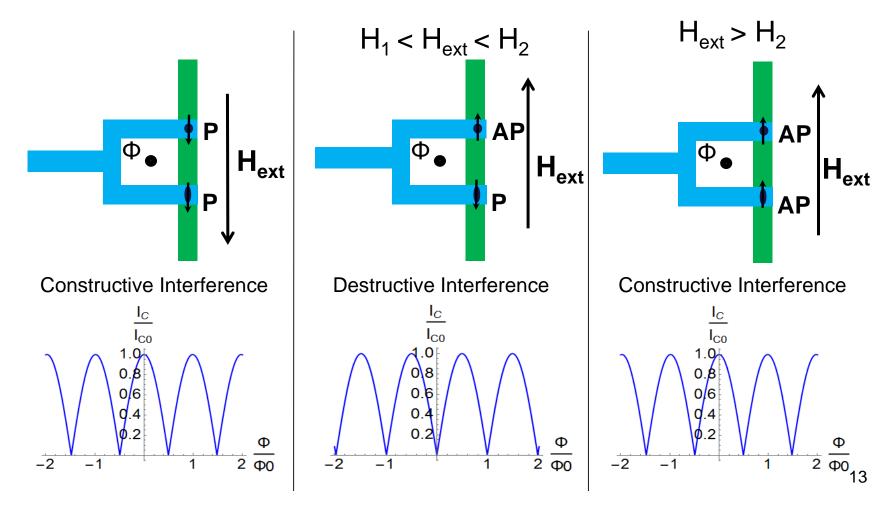


Switch magnetization with in-plane field

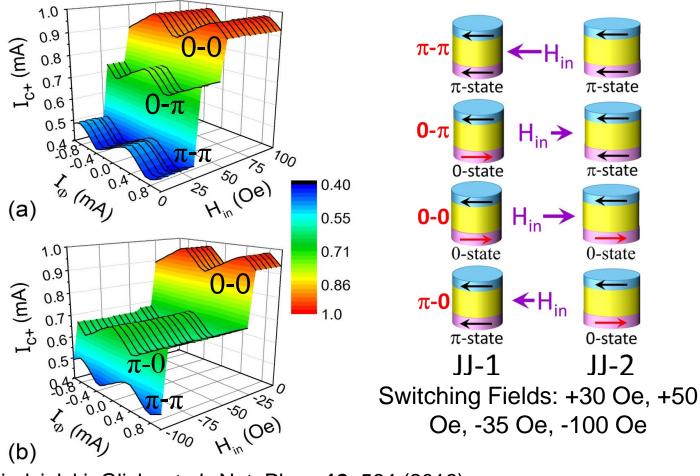
Different aspect ratio pillars have different switching fields

# At Relatively Low External Fields, Two Phase Changes Should Be Observable

Initialize with large field in -z direction, then slowly increase H<sub>ext</sub> in +z direction

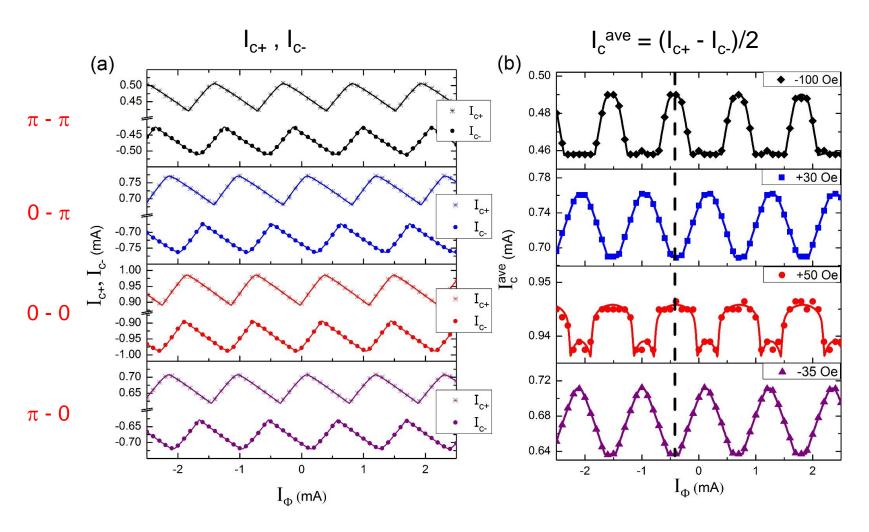


# Data show clean switching between the four expected states



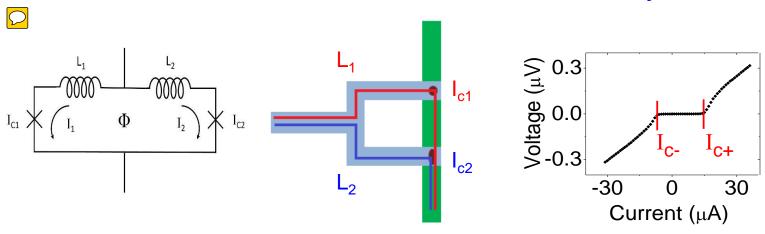
Gingrich, Niedzielski, Glick, et al., Nat. Phys. 12, 564 (2016)

# Data cuts for the four magnetic states



 $\bigcirc$ 

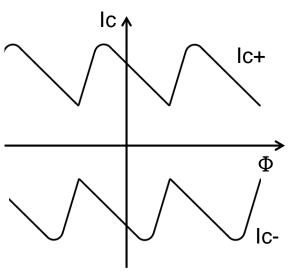
# $I_c(\Phi)$ curves have tilted ratchet shape when loop inductances and/or critical currents are asymmetric



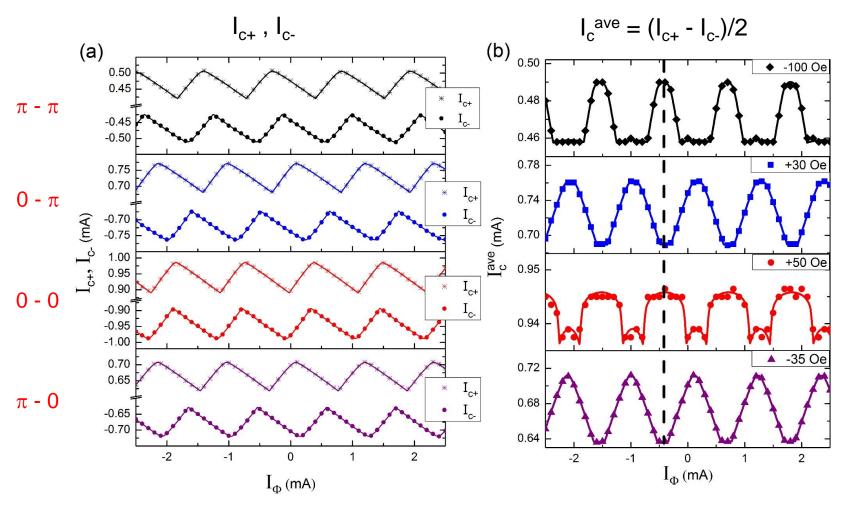
 $I_c^+(\Phi)$  and  $I_c^-(\Phi)$  oscillations are asymmetric when  $L_1 \neq L_2 \& I_{c1} \neq I_{c2}$ 

 $I_c^+$  and  $I_c^-$  shift by equal amounts and in opposite directions along the  $\Phi$  axis

Analyze I<sub>c</sub><sup>+</sup> and I<sub>c</sub><sup>-</sup> peak shifts to extract JJ phase shifts



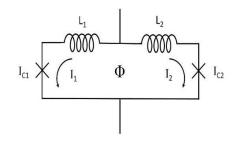
# Quantitative fits to SQUID modulation data for the four magnetic states



Gingrich, Niedzielski, Glick, et al., Nat. Phys. 12, 564 (2016)

## Quantitative Analysis Consistently Assigns the Inductance and Critical Currents of Each State

state	I <sub>c1</sub> (mA)	I <sub>c2</sub> (mA)	L <sub>1</sub> (pH)	L <sub>2</sub> (pH)
π - π	0.292	0.217	5.73	11.38
0 - π	0.565	0.203	5.64	11.33
0 - 0	0.567	0.419	5.63	11.55
π - 0	0.294	0.420	5.71	11.56
		ave (	5.68	11.46
		σ	0.05	0.12



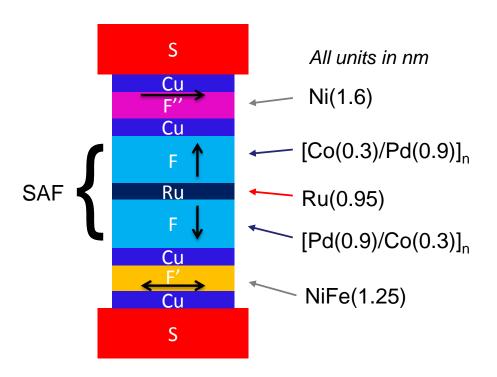
FastHenry simulations:

$$L_1 \approx 7 \text{ pH}, \quad L_2 \approx 13 \text{ pH}$$

Fitting parameters from independent fits of 4 magnetic states are highly consistent

• Exception: critical current of JJ #2 changes slightly in  $\pi$  state when JJ #1 switches from  $\pi$  to 0 state

# New result! Controllable $0-\pi$ switching with spin-triplet supercurrent



Spin-triplet supercurrent decays very slowly in F

 $0 - \pi$  switching occurs by spin rotation rather than accumulated pair phase

Spin-triplet JJ requires three F layers with non-collinear magnetizations between adjacent layers

Data are not yet available for public dissemination, but we plan to submit them for publication soon: J.A. Glick et al. (2017)



## What needs to be done

- Memory (see talk Fr-C-DIG-03 by Ofer Naaman)
  - Optimize performance of magnetic materials
    - Lower M<sub>sat</sub> ⇒ lower E<sub>switch</sub>
    - · Reduce extrinsic sources of anisotropy in thin films
    - Find better material for fixed layer (Ni has issues)
    - Minimize underlayer roughness
  - Develop read/write electronics & interface to SFQ logic
    - (see poster We-SDM-08 by Quentin Herr)
- Make the rest of the computer! (see talk Fr-I-DIG-02 by Anna Herr)

## Conclusions

- Magnetic Josephson junctions have demonstrated potential for ultra-low-power cryogenic memory
- Much more work needs to be done!

# Bibliography

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